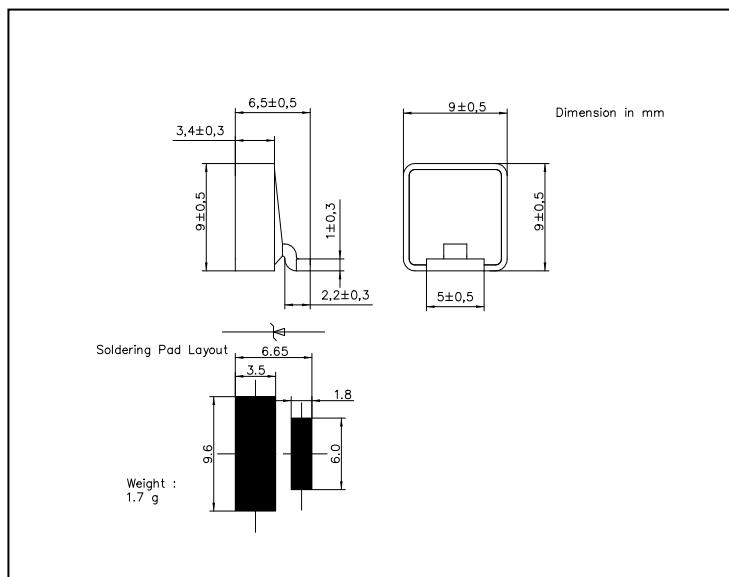


SURGE SUPPRESSOR DIODE

FEATURES

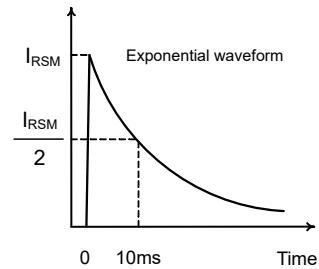
- High transient reverse power capability suitable for Load Dump Surge protecting for automobile electronic components etc.

OUTLINE DRAWING**ABSOLUTE MAXIMUM RATINGS**

Items	Symbols	Units	Ratings
Non-Repetitive Peak Reverse One-Cycle Dissipation	P _{RSM}	W	4,300(Rectangular pulse t=1ms T _j =25°C start)
Non-Repetitive Peak Reverse Surge Current	I _{RSM}	A	100(Exponential waveform. See Fig.1, T _j =25°C start)
DC Reverse Voltage	V _{DC}	V	22
Operating Junction Temperature	T _j	°C	-40 ~ +150
Storage Temperature	T _{stg}	°C	-40 ~ +150

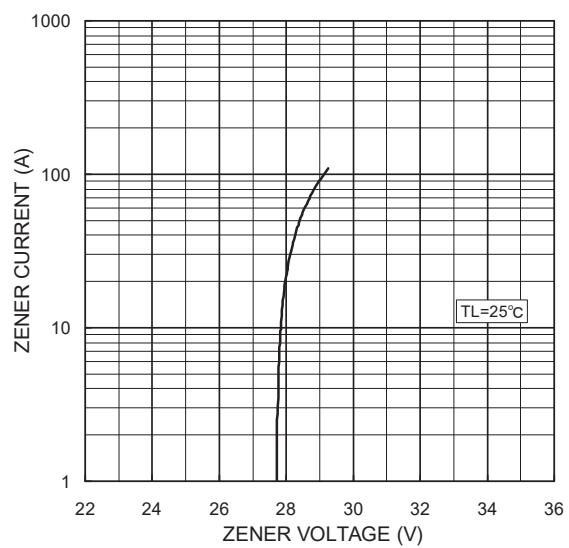
CHARACTERISTICS(T_L=25°C)

Items	Symbols	Units	Min.	Typ.	Max.	Test Conditions
Zener Voltage	V _z	V	24.0	27.0	30.0	I _z =10mA
Dynamic Impedance	Z _z	Ω	-	-	50	I _z =10mA
Zener Voltage Temperature Coefficient	γ _z	%/°C	-	0.081	-	I _z =10mA
Peak Forward Voltage	V _{FM}	V	-	-	1.2	I _{FM} =6A
Peak Reverse Current	I _{RRM}	μA	-	-	10	V _R =22V

Figure 1. I_{RSM} waveform

FZSH5MV27

Typical zener characteristics



Typical reverse power characteristics
(Rectangular pulse non-repetitive)

